

SI5905BDC-T1-GE3

SI5905BDC-T1-GE3 Information





Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



SI5905BDC-T1-GE3 Specifications

Manufacturer Part Number	SI5905BDC-T1-GE3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	8-SMD, Flat Lead
Series	TrenchFET?
FET Type	2 P-Channel (Dual)
FET Feature	Logic Level Gate
Drain to Source Voltage (Vdss)	8V
Current - Continuous Drain (Id) @ 25°C	4A
Rds On (Max) @ Id, Vgs	80 mOhm @ 3.3A, 4.5V
Vgs(th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	11nC @ 8V
Input Capacitance (Ciss) (Max) @ Vds	350pF @ 4V
Power - Max	3.1W
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	8-SMD, Flat Lead
Supplier Device Package	1206-8 ChipFET?
	Report errors?

SI5905BDC-T1-GE3 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

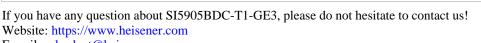


Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

SI5905BDC-T1-GE3 Payment Methods





E-mail: salesdept@heisener.com